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PATENT

Attorney Reference Number: 6047-53173

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Agarwal et al.

Art Unit: 2811

Application No. 09/590,795

CERTIFICATE OF MAILING

Filed: June 8, 2000

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For: METHODS FOR FORMING AND
INTEGRATED CIRCUIT
STRUCTURES CONTAINING
RUTHENIUM AND TUNGSTEN
CONTAINING LAYERS

Examiner: Cuong Q. Nguyen


Attorney for Applicant

Date: June 24, 2003

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Listed on the accompanying form PTO-1449 and enclosed herewith are several English-language documents. Applicants respectfully request that these documents be listed as references cited on the issued patent.

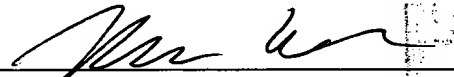
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The filing of this IDS shall not be construed to be an admission that the information cited in the statement is, or is considered to be, prior art or otherwise material to patentability as defined in Rule 56.

Respectfully submitted,

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